

SURFACE MOUNT HIGH SPEED SILICON SWITCHING DIODE



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DESCRIPTION:

The CENTRAL SEMICONDUCTOR CLL4150 type is an ultra-high speed silicon switching diode manufactured by the epitaxial planar process, in a hermetically sealed glass surface mount package, designed for high speed switching applications.

MARKING: CATHODE BAND

MAXIMUM RATINGS: (T _A =25°C)	SYMBOL		UNITS
Continuous Reverse Voltage	V _R	50	V
Peak Repetitive Reverse Voltage	V _{RRM}	50	V
Continuous Forward Current	۱ _F	300	mA
Peak Repetitive Forward Current	I _{FRM}	600	mA
Peak Forward Surge Current, tp=1.0µs	I _{FSM}	4.0	А
Peak Forward Surge Current, tp=1.0s	IFSM	1.0	А
Power Dissipation	PD	500	mW
Operating and Storage Junction Temperature	T _J , T _{stg}	-65 to +200	°C
Thermal Resistance	Θ_{JA}	350	°C/W
ELECTRICAL CHARACTERISTICS: (T _A =25°C unl	ess otherwise noted)	МАХ	LINITS

SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
I _R	V _R =50V		100	nA
BVR	Ι _R =5.0μΑ	75		V
V _F	I _F =1.0mA	0.54	0.62	V
V _F	I _F =10mA	0.66	0.74	V
V _F	I _F =50mA	0.76	0.86	V
V _F	I _F =100mA	0.82	0.92	V
V _F	I _F =200mA	0.87	1.0	V
CT	V _R =0, f=1.0 MHz		4.0	pF
t _{rr}	$I_R=I_F=10$ mA, $R_L=100\Omega$, Rec. to 1.0mA		4.0	ns

R3 (8-January 2010)

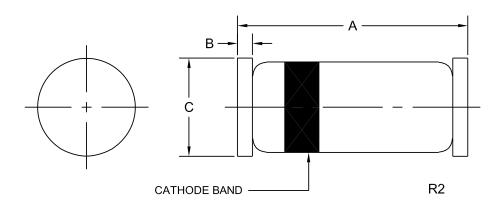






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SOD-80 CASE - MECHANICAL OUTLINE



MARKING: CATHODE BAND

DIMENSIONS							
	INCHES		MILLIMETERS				
SYMBOL	MIN	MAX	MIN	MAX			
А	0.130	0.146	3.30	3.71			
В	0.014		0.35				
C (DIA)	0.049	0.067	1.25	1.70			
SOD-80 (REV:R2)							

R3 (8-January 2010)

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OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- Environmental regulation compliance
- Customer specific screening
- Up-screening capabilities

Special wafer diffusions

· Custom product packing

- PbSn plating options
- Package details
- Application notes
- Application and design sample kits

· Custom bar coding for shipments

Custom product and package development

REQUESTING PRODUCT PLATING

- 1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
- 2. If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

CONTACT US

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